

# **Agilent HCPL-3180 2 Amp Output Current, High Speed IGBT/MOSFET Gate Drive Optocoupler**

Data Sheet

# **Description**

This family of devices consists of a GaAsP LED. The LED is optically coupled to an integrated circuit with a power stage. These optocouplers are ideally suited for high frequency driving of power IGBT and MOSFETs used in Plasma Display Panels, high performance DC/DC convertors and motor control invertor applications.

### **Ordering Information**

Specify part number followed by option number (if desired):

Example : HCPL-3180-XXX



### **Functional Diagram**

No option = Standard DIP package, 50 per tube.

Option, 50 per tube.

Option.

approval)

300 = Gull Wing Surface Mount

500 = Tape and Reel Packaging

060 = DIN EN 60747-5-2 Option, VIORM=630 Vpeak (pending

# **Features**

- **• 2 A minimum peak output current**
- **• 250 KHz maximum switching speed**
- **• High speed response: 200 ns max Propagation delay over temperature range**
- **• 10 KV/us minimum common mode rejection (CMR) at V<sub>CM</sub>=1500 V**
- **• Under voltage lockout protection (UVLO) with hysteresis**
- **• Wide operating temperature range: -40 °C to +100 °C**
- Wide V<sub>CC</sub> operating range: **10 V to 20 V**
- **• 20 ns typ pulse width distortion**

**• Safety Approvals: UL approval pending 3750 VRMS for 1 minute. CSA approval DIN EN 60747-5-2 approval pending**

### **Applications**

- **• Plasma Display Panel (PDP)**
- **• Distributed power architecture (DPA)**
- **• Switch mode rectifier (SMR)**
- **• High performance DC/DC convertor**
- **• High performance switch mode power supply (SMPS)**
- **• High performance uninterruptible power supply (UPS)**
- **• Isolated IGBT/Power MOSFET gate drive**

A 0.1 uF bypass capacitor must be connected between pins 5 and 8.

CAUTION: It is advised that normal static precautions be taken in handling and assembly of this component to prevent damage and/ or degradation which may be induced by ESD.



### **HCPL-3180 Standard DIP Package**



# **HCPL-3180 Gull Wing Surface Mount Option 300**



# **Solder Reflow Temperature Profile**



### **Regulatory Information**

The HCPL-3180 is pending approval by the following organizations:

# **DIN EN 60747-5-2**

Pending approval under DIN EN-60747-5-2 with  $V_{\text{IORM}} = 630$  $V<sub>PEAK</sub>$ 

# **UL**

Approval under UL 1577, component recognition program up to  $V_{\rm ISO}$  = 2500  $V_{\rm RMS.}$  Pending 3750 VRMS.

# **CSA**

Approval under CSA Component.



# **DIN EN 60747-5-2 Insulation Characteristics (HCPL-3180 Option 060)**

\* Refer to the optocoupler section of the Isolation and Control Components Designer's Catalog, under Product Safety Regulations section, (DIN) for a detailed description of Method A and Method B partial discharge test profiles.

\*\* Refer to the following figure for dependence of  $P_S$  and  $I_S$  on ambient temperature.



# **Insulation and Safety Related Specifications**



# **Absolute Maximum Ratings**



# **Recommended Operating Conditions**



# **Electrical Specifications (DC)**

Over recommended operating conditions unless otherwise specified.



# **Switching Specifications (AC)**

Over recommended operating conditions unless otherwise specified.



### **Package Characteristics**



#### **Notes:**

- 1. Derate linearly above +70 °C free air temperature at a rate of 0.3 mA/°C.
- 2. Maximum pulse width = 10 us, maximum duty cycle = 0.2%. This value is intended to allow for component tolerances for designs with  $I_0$  peak minimum = 2.0 A. See Application section for additional details on limiting  $I_{OL}$  peak.
- 3. Derate linearly above +70 °C, free air temperature at the rate of 4.8 mW/°C.
- 4. Derate linearly above +70 °C, free air temperature at the rate of 5.4 mW/°C. The maximum LED junction temperature should not exceed +125 °C.
- 5. Maximum pulse width  $= 50$  us, maximum duty cycle  $= 0.5$ %.
- 6. In this test, V<sub>OH</sub> is measured with a dc load current. When driving capacitive load V<sub>OH</sub> will approach V<sub>CC</sub> as I<sub>OH</sub> approaches zero amps.
- 7. Maximum pulse width  $= 1$  ms, maximum duty cycle  $= 20\%$ .
- 8. In accordance with UL 1577, each optocoupler is proof tested by applying an insulation test voltage > 3000 V<sub>rms</sub> for 1 second (leakage detection current limit  $I_{1-0}$  < 5 uA).
- 9. Device considered a two-terminal device: pins on input side shorted together and pins on output side shorted together.
- 10. tp<sub>HL</sub> propagation delay is measured from the 50% level on the falling edge of the input pulse to the 50% level of the falling edge of the V<sub>O</sub> signal. t<sub>PLH</sub> propagation delay is measured from the 50% level on the rising edge of the input pulse to the 50% level of the rising edge of the  $V_0$  signal
- 11. t<sub>PSK</sub> is equal to the magnitude of the worst case difference in t<sub>PHL</sub> and/or t<sub>PLH</sub> that will be seen between units at any given temperature within the recommended operating conditions
- 12. PWD is defined as  $|t_{PHL} \cdot t_{PLH}|$  for any given device.
- 13. Pin 1 and 4 need to be connected to LED common.
- 14. Common mode transient immunity in the high state is the maximum tolerable dV<sub>CM</sub>/dt of the common mode pulse V<sub>CM</sub> to assure that the output will remain in the high state (i.e.  $V_0$  > 10.0 V).
- 15. Common mode transient immunity in a low state is the maximum tolerable dV<sub>CM</sub>/dt of the common mode pulse, V<sub>CM</sub>, to assure that the output will remain in a low state (i.e.  $V_0$  < 1.0 V).
- 16. tpHL propagation delay is measured from the 50% level on the falling edge of the input pulse to the 50% level of the falling edge of the V<sub>O</sub> signal. t<sub>PLH</sub> propagation delay is measured from the 50% level on the rising edge of the input pulse to the 50% level of the rising edge of the V<sub>O</sub> signal
- 17. The difference between t<sub>PHL</sub> and t<sub>PLH</sub> between any two HCPL-3180 parts under same test conditions.





**Figure 1. V<sub>OH</sub> Vs Temperature** 



**Figure 2. I<sub>OH</sub> Vs Temperature** 

**Figure 3. VOH Vs IOH**



**Figure 4. V<sub>OL</sub> Vs Temperature** 



**Figure 5. IOL Vs Temperature**



Figure 6. V<sub>OL</sub> Vs I<sub>OL</sub>







**Figure 8. Icc Vs Vcc** 







**Figure 10. Propagation Delay Vs V<sub>CC</sub>** 



**Figure 11. Propagation Delay Vs IF**



**Figure 12. Propagation Delay Vs Temperature**



**Figure 13. Propagation Delay Vs Rg**







**Figure 15. Transfer Characteristics**



**Figure 16. Input Current Vs Forward Voltage**







**Figure 17. IOH Test Circuit**



**Figure 18. IOL Test Circuit**

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**Figure 19. VOH Test Circuit**



**Figure 20. VOL Test Circuit**



**Figure 21. IFLH Test Circuit**



**Figure 22. UVLO Test Circuit**





**Figure 23. TPLH, TPHL, Tr and Tf Test Circuit and Waveform**



**Figure 24. CMR Test Circuit and Waveform**

# **Applications Information Eliminating Negative IGBT Gate Drive**

To keep the IGBT firmly off, the HCPL-3180 has a very low maximum  $V_{OL}$  specification of 0.4 V. The HCPL-3180 realizes the very low  $V_{OL}$  by using a DMOS transistor with 1 W (typical) on resistance in its pull down circuit. When the HCPL-3180 is in the low state, the IGBT gate is shorted to the emitter by Rg + 1 W. Minimizing Rg and the lead inductance from the HCPL-3180 to the IGBT gate and emitter (possibly by mounting HCPL-3180 on a small PC board directly above the IGBT) can eliminate the need for negative IGBT gate drive in many applications as shown in Figure 25. Care should be taken with such a PC board design to avoid routing the IGBT collector or emitter traces close to the HCPL-3180 input as this can result in unwanted coupling of transient signals into the input of HCPL-3180 and degrade performance.

(If the IGBT drain must be routed near the HCPL-3180 input, then the LED should be reverse biased when in the off state, to prevent the transient signals coupled from the IGBT drain from turning on the HCPL-3180)

# **Selecting the Gate Resistor (Rg) for HCPL-3180**

**Step 1:** Calculate R<sub>g</sub> minimum from the  $I<sub>OL</sub>$  peak specification. The IGBT and  $R<sub>g</sub>$  in Figure 25 can be analyzed as a simple RC circuit with a voltage supplied by the HCPL-3180.

$$
R_g \ge \frac{V_{CC} - V_{OL}}{I_{OLPEAK}}
$$
  
= 
$$
\frac{20 - 3}{2}
$$
  
= 8.5Ω

The V<sub>OL</sub> value of 3 V in the previous equation is the VOL at the peak current of 2 A. (See Figure 6).

**Step 2:** Check the HCPL-3180 power dissipation and increase Rg if necessary. The HCPL-3180 total power dissipation  $(P_T)$  is equal to the sum of the emitter power  $(P_E)$  and the output power  $(P<sub>0</sub>)$ .

$$
\begin{array}{l} P_T = P_E + P_O \\ P_E = I_F \bullet V_F \bullet DutyCycle \\ P_O = P_{O(BIAS)} + P_{O(SWfICHING)} \\ = I_{CC} \bullet V_{CC} + E_{SW}(R_g; Q_g) \bullet f \\ = (I_{CC}) \bullet V_{CC} + E_{SW}(R_g; Q_g) \bullet f \end{array}
$$

For the circuit in Figure 25 with the circuit in with  $I_F$  (worst

case) = 16 mA,  $R_g \approx 10 \text{ W}$ , Max Duty Cycle =  $80\%$ ,  $Q_g = 100$  nC, f = 200 kHz and  $T_{AMAX}$  = +75 °C:

$$
P_E = 16mA \cdot 1.8V \cdot 0.8 = 23mW
$$
  
\n $P_O = 4.5mA \cdot 20V + 0.85 \mu J \cdot 200kHz$ 

$$
=260 \text{mW} \ge 226 \text{mW} \begin{pmatrix} P_{\text{O(MAX)}} \omega \\ 75^{\circ}C \\ =250 \text{mW} \\ -(5^{\circ}C)^{*} \\ 4.8 \text{mW} / ^{\circ}C) \end{pmatrix}
$$

The value of 4.5 mA for  $I_{CC}$  in the previous equation was obtained by derating the  $I_{CC}$  max of 6 mA to  $I_{CC}$  max at +75 °C. Since  $P_0$  for this case is greater than the  $P_{O(max)}$ , Rg must be increased to reduce the HCPL-3180 power dissipation.

```
=136mW= 226 mW - 90 mW= P_0 (Max) - P_0 (Bias)P_o(SwitchingMAX)
```
 $= 0.68 \mu W$  $=136mW/200KHz$  $= P_{\text{O}(Stiching Max)} / f$  $\mathrm{E_{SW(Max)}}$ 

For  $Qg = 100$  nC a Value of Esw = 0.68 UW gives a Rg = 15 ohm



**Figure 25. Recommended LED Drive and Application Circuit for HCPL-3180**







**Figure 27. Energy Dissipated in the HCPL-3180 for each IGBT**

### **Thermal Model**

#### **(Discussion applies to HCPL-3180)**

The steady state thermal model for the HCPL-3180 is shown in Figure 28. The thermal resistance values given in this model can be used to calculate the temperatures at each node for a given operating condition. As shown by the model, all heat generated flows through  $Q_{CA}$  which raises the case temperature  $T_C$  accordingly. The value of  $Q_{CA}$  depends on the conditions of the board design and is, therefore, determined by the designer. The value of  $Q_{CA} = +83 \degree C/W$  was obtained from thermal measurements using a 2.5 x 2.5 inch PC board, with small traces (no ground plane), a single HCPL- 3180 soldered into the center of the board and still air. The absolute maximum power dissipation derating specifications assume a  $\mathbb{Q}_{CA}$  value of +83 °C/W From the thermal mode in Figure 28 the LED and detector IC junction temperatures can be expressed as:

$$
T_{JE} = P_E * (\theta_{LC} // (\theta_{LD} + \theta_{DC}) + \theta_{CA} + P_D * (\frac{\theta_{LC} * \theta_{DC}}{\theta_{LC} + \theta_{DC} + \theta_{LD}} + \theta_{CA}) + T_A
$$
  

$$
T_{JD} = P_E * (\frac{\theta_{LC} * \theta_{DC}}{\theta_{LC} + \theta_{DC} + \theta_{LD}} + \theta_{CA}) + P_D * (\theta_{DC} // (\theta_{LD} + \theta_{LC}) + \theta_{CA}) + T_A
$$

Inserting the values for QLC and QDC shown in Figure 28 gives:

 $T_{JE}$  = PE·(+256 °C/W + Q<sub>CA</sub>)+ PD·(+57 °C/W + Q<sub>CA</sub>) +  $T_A$  $T_{JD}$  = PE·(+57 °C/W + Q<sub>CA</sub>)+ PD·(+111 °C/W + Q<sub>CA</sub>) +  $T_A$ 

For example, given  $P_E = 45$  mW,  $P_{O} = 250$  mW,  $T_{A} = +70$  °C and QCA= +83 °C/W:  $T_{JE}$  = PE·(+339 °C/W + PD·(+140 °C/W +  $T_A$  $= 45$  mW $+339$  °C/W + 250 mW $+140$  °C/W +  $+70$  °C  $= +120 °C$  $T_{JD}$  = PE·(+140 °C/W + PD·+194 °C/W + $T_A$  $= 45$  mW·+140 °C/W + 250 mW·+194 °C/W + +70 °C  $= +125$  °C

 $T_{\text{JE}}$  and  $T_{\text{JD}}$  should be limited to +125 °C based on the board layout and part placement (QCA) specific to the application.

15 TJE = LED junction temperature TJD = detector IC junction temperature  $TC = \text{case temperature measured at the center of the package bottom}$  $Q_{LC}$  = LED-to-case thermal resistance  $Q_{LD}$  = LED-to-detector thermal resistance  $Q_{DC}$  = detector-to-case thermal resistance  $Q_{CA}$  = case-to-ambient thermal resistance  $^*$ Q<sub>CA</sub> will depend on the board design and the placement of the part.

### **LED Drive Circuit Considerations for Ultra High CMR Performance**

Without a detector shield, the dominant cause of optocoupler CMR failure is capacitive coupling from the input side of the optocoupler, through the package, to the detector IC as shown in Figure 29. The HCPL-3180 improves CMR performance by using a detector IC with an optically transparent Faraday shield, which diverts the capacitively coupled current away from the sensitive IC circuitry. However, this shield does not eliminate the capacitive coupling between the LED and optocoupler pins 5-8 as shown in Figure 30. This capacitive coupling causes perturbations in the LED current during common mode transients and becomes the major source of CMR failures for a shielded optocoupler. The main design objective of a high CMR LED drive circuit becomes keeping the LED in the proper state (on or off ) during common mode transients. For example, the recommended application circuit (Figure 25), can achieve 10 kV/us CMR while minimizing component complexity.

Techniques to keep the LED in the proper state are discussed in the next two sections.







**Figure 30. Optocoupler Input to Output Capacitance Model for Shielded Optocouplers.**







**Figure 32. Not Recommended Open Collector Drive Circuit.**

**Figure 33. Recommended LED Drive Circuit for Ultra-High CMR**

### **CMR with the LED On (CMRH)**

A high CMR LED drive circuit must keep the LED on during common mode transients. This is achieved by over-driving the LED current beyond the input threshold so that it is not pulled below the threshold during a transient. A minimum LED current of 10 mA provides adequate margin over the maximum I<sub>FLH</sub> of 8 mA to achieve 10 kV/us CMR.

### **CMR with the LED Off (CMRL)**

A high CMR LED drive circuit must keep the LED off ( $V_F \leq$  $V_{\text{F(OFF)}}$ ) during common mode transients. For example, during a -dV $_{CM}/dt$  transient in Figure 31, the current flowing through CLEDP also flows through the R<sub>SAT</sub> and V<sub>SAT</sub> of the logic gate. As long as the low state voltage developed across the logic gate is less than  $V_{F(OFF)}$  the LED will remain off and no common mode failure will occur.

The open collector drive circuit, shown in Figure 32, cannot keep the LED off during a  $+dV_{CM}/dt$ transient, since all the current flowing through CLEDN must be supplied by the LED, and it is not recommended for applications requiring ultra high CMRL performance. Figure 33 is an alternative drive circuit, which like the recommended application circuit (Figure 25), does achieve ultra high CMR performance by shunting the LED in the off state.

### **Under Voltage Lockout Feature**

The HCPL-3180 contains an under voltage lockout (UVLO) feature that is designed to protect the IGBT under fault conditions which cause the HCPL-3180 supply voltage (equivalent to the fully charged IGBT gate voltage) to drop below a level necessary to keep the IGBT in a low resistance state. When the HCPL-3180 output is

in the high state and the supply voltage drops below the HCPL-3180 U<sub>VLO</sub>-threshold (typ  $7.5$  V) the optocoupler output will go into the low state. When the HCPL-3180 output is in the low state and the supply voltage rises above the HCPL-3180  $V<sub>UVLO+</sub>$  threshold (typ 8.5 V) the optocoupler output will go into the high state (assume LED is "ON").

# **IPM Dead Time and Propagation Delay Specifications**

The HCPL-3180 includes a Propagation Delay Difference (PDD) specification intended to help designers minimize "dead time" in their power invertor designs. Dead time is the time during which the high and low side power transistors are off. Any overlap in Q1 and Q2 conduction will result in large currents flowing through the power devices from the high voltage to the low-voltage motor rails.







\*PDD = PROPAGATION DELAY DIFFERENCE NOTE: FOR PDD CALCULATIONS THE PROPAGATION DELAYS ARE TAKEN AT THE SAME TEMPERATURE AND TEST CONDITIONS.

**Figure 35. Minimum LED Skew for Zero Dead Time**

To minimize dead time in a given design, the turn on of LED2 should be delayed (relative to the turn off of LED1) so that under worst-case conditions, transistor Q1 has just turned off when transistor Q2 turns on, as shown in Figure 35. The amount of delay necessary to achieve this condition is equal to the maximum value of the propagation delay difference specification,  $PDD<sub>MAX</sub>$ , which is specified to be 90 ns over the operating temperature range of -40 °C to +100 °C.

Delaying the LED signal by the maximum propagation delay difference ensures that the minimum dead time is zero, but it does not tell a designer what the maximum dead time will be. The maximum dead time is equivalent to the difference between the maximum and minimum propagation delay difference specification as shown in Figure 36. The maximum dead time for the HCPL-3180 is 180 ns (= 90 ns-(- 90 ns)) over the operating temperature range of –40 °C to  $+100 °C$ .

Note that the propagation delays used to calculate PDD and dead time are taken at equal temperatures and test conditions since the optocouplers under consideration are typically mounted in close proximity to each other and are switching identical IGBTs.



\*PDD = PROPAGATION DELAY DIFFERENCE NOTE: FOR DEAD TIME AND PDD CALCULATIONS ALL PROPAGATION<br>DELAYS ARE TAKEN AT THE SAME TEMPERATURE AND TEST CONDITIONS.

**Figure 36. Waveforms for Dead Time**

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